DCCT GS09DT-ML, mounted in the SIS18 (GSI development)



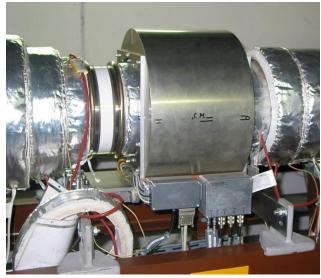
• Chamber for UHV, bakeable upto 300°C

• Aperture: DN200CF

• Length: 600mm

• Al₂O₃ ceramic gap, resistive coating on inner surface

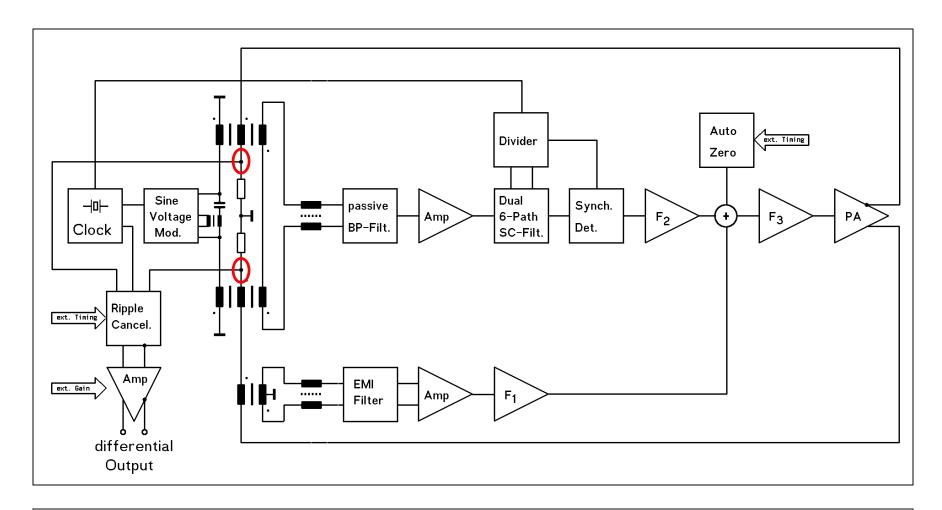
• Dual-layer Mumetal® magnetic shield





- Remote control / ADC placed outside of tunnel
- Locally mounted 19" front end electronics (see bottom)
- DCCT upgraded with 2 V/f-converter outputs:
- o fixed range 1 MHz f. s. / 60mA beam current
- o 1MHz f.s. for each selected range

GSI DCCT block diagram



=> differential voltage proportional to DC beam current / U_{diff} ~ I_{beam}, * 16.66 V/A, dynamic range ≥ 100 dB

GSI DCCT: A magnetic modulator with the usual 3-core scheme

• Dimensions of toroids: 264 x 284 x 10 mm

• Magnetic ribbons: VITROVAC® 6025F, t = 25 µm

• Winding schemes: $N_{loop}=12$, $N_{DC}=16$, $N_{AC}=96$, $N_{mod}=16$

• Main control loop: Current driven, burden resistance 200 Ω

• Control sub-loops: Peak modulation current, Auto-Zero

• Modulation characteristics: Sine voltage, with avalanche capacitor

• Modulation frequency: 987.5 Hz

• Peak excitation field: ~ 20 A/m

• Crossover frequency DC/AC channel: ~ 6 Hz

• Open loop gain at DC: >120 dB

• Open loop - 0 dB crossing frequency: ~ 0.4 Mhz

• Signal transmission, toroids to front end: differential, twisted pair lines

• Cable length, toroids to front end: 2.5 m, limited by cable capacitances

• Min. Shunt impedance @ DC: ≥ 2 kΩ, across toroid stack

GSI GS09DT-ML DCCT Specifications

• 8 Current Ranges: ± 300 µA to 1 A DC f. s., (1... 3 ... 10 ...)

• Bunched Beam Current Limit: ~ 40 – 100 mA, dependent on bunch frequency / harmonic no.

• DC Gain error: $\leq 0.1 \%$ (for I < 50 mA)

• DC Linearity error: $\leq 0.1 \%$ (for I < 50 mA)

• 1/f-noise corner frequency: ~ 2 Hz

• Offset Temperature coefficient: ~ 5 µA/°C

• Auto-Zero function: active during time gap between 2 consecutive acc. cycles

• Zero error absolute: $\pm \sim 2.5 \mu A$

toroid

• Zero Error due to external mag. fields: ~ 6 µA / T of main dipole field

• Current resolution: ~ 5 μApp @ 20 kHz bandwidth (~1 μArms), S/N=1, range 100 μA

• Output bandwidth: DC .. ~ 2 kHz (small signal; new output sample every ~ 506 μs)

• Ripple cancellation: 2 * f_{Mod}-synchroneous sampling at zero-crossing of output signal

• Test current: pulse of 5ms duration and ~50% f.s. amplitude (matched to the

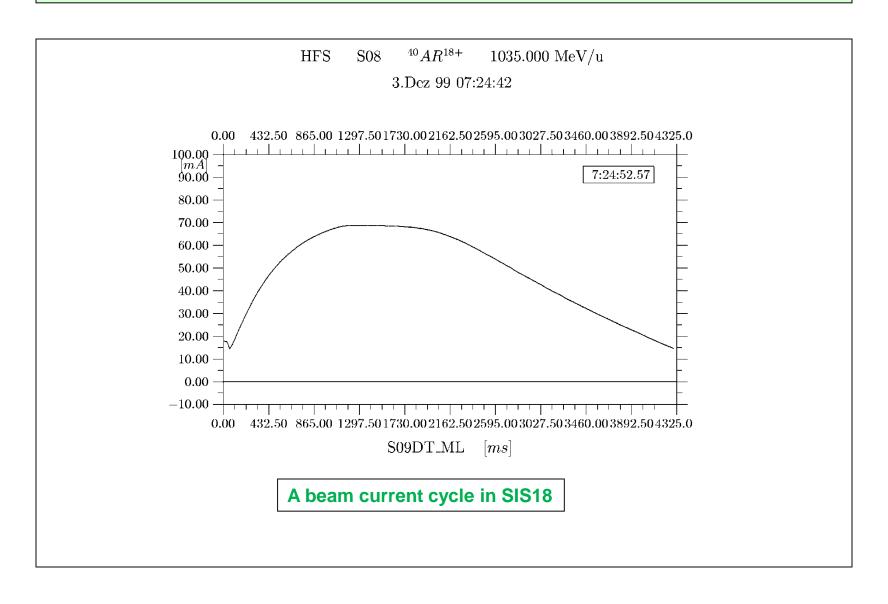
selected current range), injected into a single turn around the

set

• Built-in Voltage-to-frequeny converters : TTL 50Ω output, Ch1: $f_{max} = 1$ MHz @ 60 mA beam current

Ch2: $f_{max} = 1MHz$ for each f.s. range

Typical operation of GSI/SIS18 DCCT at higher beam intensity



Typical operation of GSI/SIS18 DCCT at low beam intensity

